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## GVBL-T14GD

- PN-type UV Photodiode
- InGaN based
- 345 – 445 nm
- TO-46 Package



### Description



**GVBL-T14GD** is InGaN based PN-type UV broadband photodiode in metal TO-46 package with high Responsivity & low dark current. It is intended for photovoltaic mode operation, and is primarily used for UV LED monitoring.

### Maximum Ratings\*

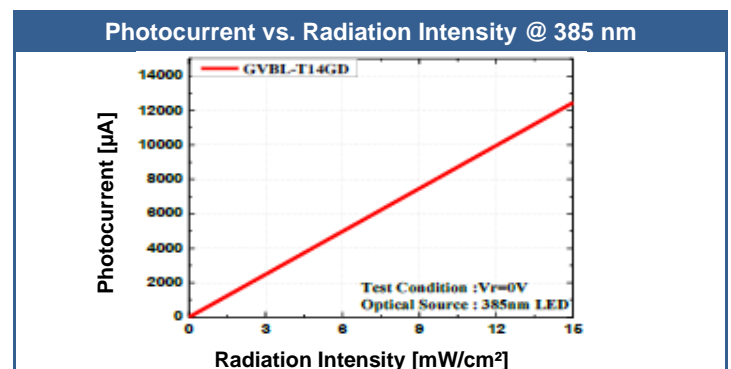
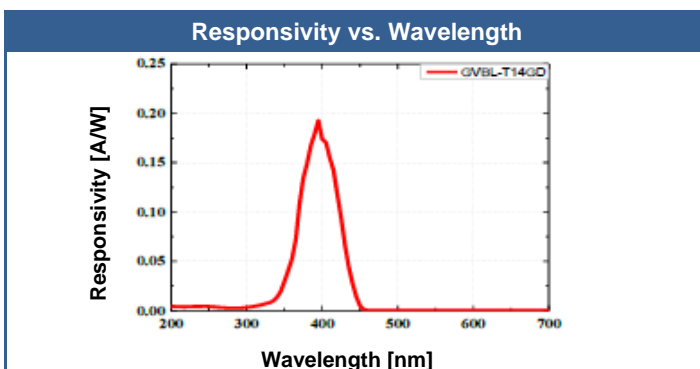
Parameter	Symbol	Values		Unit
		Min.	Max.	
Reverse Voltage	$U_R$		5	V
Forward Current	$I_F$		1	mA
Dark Current ( $V_R = 0.1$ V)	$I_D$		1	nA
Operating Temperature	$T_{OP}$	- 30	+ 85	°C
Storage Temperature	$T_{ST}$	- 40	+ 90	°C
Lead Solder Temperature ( $t_{max.}$ 10s)	$T_{SLD}$		+ 260	°C

\*Operating close to or exceeding these parameters may damage the device

### Electro-Optical Characteristics ( $T_{CASE} = 25^\circ\text{C}$ )

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Spectral Detection Range	$\lambda_D$	10% of R	345		445	nm
Photo Current	$I_P$	385nm, 1 mW/cm <sup>2</sup>		830		nA
Responsivity	$R$	$\lambda = 385$ nm, $V_R = 0$ V		0.17		A/W
Viewing Angle	$\theta$			120		degree

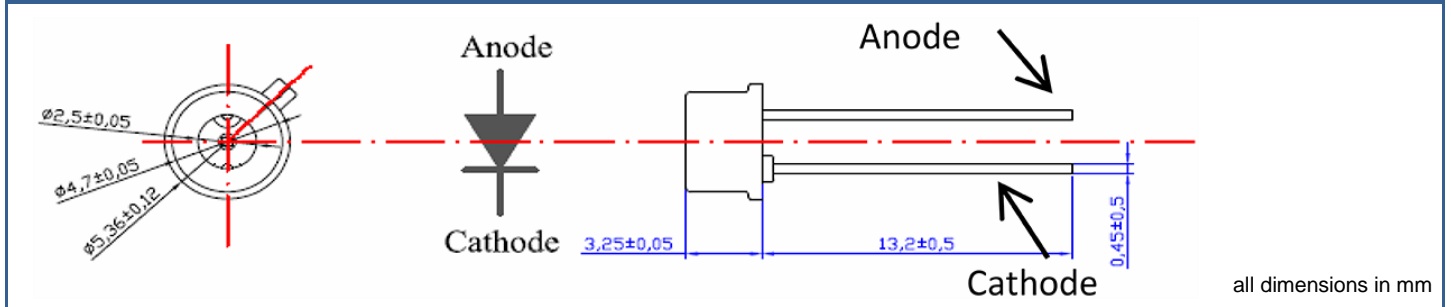
### Typical Performance Curves





## Outline Dimensions

TO-46



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The above specifications are for reference purpose only and subjected to change without prior notice